

**Vishay Siliconix** 

# 6 A, 33 m $\Omega$ , 2.8 V to 23 V, eFuse With Programmable Current Limit and OVP

#### DESCRIPTION

The SIP32434A and SIP32434B are single-channel eFuses that integrate multiple control and protection features, which provide increased controllability and reliability, with simplified designs and minimal external components.

The SIP32434A and SIP32434B protect both power sources and downstream circuitry connected to the switch from overloads, short circuits, voltage surges, and excessive inrush currents.

The output current limit can be set by a single external resistor.  $V_{\rm IN}$  overvoltage protection and undervoltage lockout threshold levels can be set with an external resistor network.  $V_{\rm IN}$  inrush current requirements can be set with a single external soft start capacitor.

Upon switch-off due to latchable faults, the SIP32434A will latch the power switch off and the PGD will remain low. The switch can restart by resetting the EN or V<sub>IN</sub>. The SIP32434B will auto retry if there is no OTP or OVP fault. The retry delay time is 32 times the soft start time set by the CSS.

The switch is characterized for operation over a junction temperature range of -40  $^{\circ}$ C to +125  $^{\circ}$ C.

#### APPLICATIONS

- Industrial
- IoT and smart home
- Medical and healthcare equipment
- Network and telecom equipment
- Data storage, solid state drives
- Computing
- PLC
- Lighting
- · Gaming consoles

#### **TYPICAL APPLICATION CIRCUIT**

### FEATURES

- 2.8 V to 23 V operation voltage
- 28 V max. voltage rating with 24 V internal OVP
- 33 m $\Omega$  typical switch resistance
- 0.5 A to 6 A current limit setting range
- Current limit accuracy of ± 7 %
- Fast short circuit protection response
- OCP triggering without overhead current
- Programmable turn-on slew rate
- Turn-on delay: 190 µs
- Adjustable OVP (and fixed 24 V OVP at V<sub>IN</sub>)
- Adjustable UVLO
- Over-temperature protection
- ESD / HBM: > 2 kV
- ESD / CDM: > 750 V
- · PGD: power good indicator output
- Compact TDFN10 3 mm x 3 mm package (for AEC-Q100 qualified automotive applications, please refer to SIPQ32434)
- Active reverse blocking feature available with SIP32433
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



Fig. 1 - Application Circuit

1 For technical questions, contact: <u>powerictechsupport@vishay.com</u> Document Number: 63147



ORDERING INFORMATION										
PART NUMBER	OCP RESPONSE	R <sub>DS(on</sub> (mΩ)	TRUE REVERSE CURRENT BLOCKING	REPORT	MARKING CODE	PACKAGE				
SIP32434ADN-T1E4	Latch	33	No	PG	2434A	DFN10 3 mm x 3 mm				
SIP32434BDN-T1E4	Auto-retry	33	No	PG	2434B	DFN10 3 mm x 3 mm				
SIP32434AEVB	Evaluation board									
SIP32434BEVB		Evaluation board								

#### Note

• For AEC-Q100 qualified automotive applications, please refer to SIPQ32434ADN-T1E4 and SIPQ32434BDN-T1E4

PARAMETER	CONDITION	LIMIT	UNIT	
Input voltage (V <sub>IN</sub> )	Reference to GND	-0.3 to +28		
Output voltage (V <sub>OUT</sub> )	Reference to GND	-0.3 to (V <sub>IN</sub> + 0.3) or 28, whichever comes first		
		-5 V for +5 μs		
EN voltage	Reference to GND	-0.3 to +28	V	
OVP	Reference to GND	-0.3 to +6.0		
SS	Reference to GND	-0.3 to +6.0		
I <sub>LIM</sub>		-0.3 to +6.0		
PGD		-0.3 to +6.0		
Maximum continuous switch current	SIP32434	6	А	
Thermal resistance ( <sub>thJA</sub> )		44.8	°C/W	
ESD rating	HBM	± 2		
ESD rating	CDM	± 0.75	kV	
Latch up current (V <sub>IN</sub> and V <sub>OUT</sub> )		200	mA	
Temperature		· · ·		
Operating junction temperature -40 to 150				
Maximum operating junction temperature		+150	°C	
Storage temperature		-65 to +150		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE						
ELECTRICAL	LIMIT	UNIT				
Input voltage (V <sub>IN</sub> )	3 to 23	V				
Operating junction temperature	-40 to +125	°C				



ELECTRICAL SPECIFIC	TIONS						
		TEST CONDITIONS UNLESS SPECIFIED					
PARAMETER	SYMBOL	$V_{IN} = 12 \text{ V}, \text{ T}_{J} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C},$ $V_{EN(H)} = 2.4 \text{ V},  C_{OUT} = 0.1  \mu\text{F},  \text{R}_{LIM} = 4.1  \text{k}\Omega$	MIN.	TYP.	MAX.	UNIT	
Power Supply		$V_{EN(H)} = 2.4 V$ , $C_{OOT} = 0.1 \mu$ , $H_{EIM} = 4.1 H_{22}$					
Power input voltage	V <sub>IN</sub>	Operating input voltage range	2.8	-	28	V	
Quiescent current	I <sub>Q(ON)</sub>	$EN = 1.8 \text{ V}, V_{IN} = 2.8 \text{ V} \text{ to } 28 \text{ V}, V_{OUT} \text{ open}$	-	230	340		
Shutdown current		$V_{IN} = 2.8 \text{ V to } 28 \text{ V}, \text{ EN} = 0 \text{ V}, \text{ T}_{A} = 25 \text{ °C}$	_	0.8	5	μA	
OVP switch-off current	I <sub>Q(OVP)</sub>	$V_{IN} = 2.8 \text{ V} \text{ to } 28 \text{ V}, \text{ EN} = 2.4 \text{ V}, \text{ OVP} = 1.4 \text{ V}$	_	1	-	- <sup>μ</sup> Λ	
V <sub>IN</sub> ULVO	·Q(OVF)				L		
Switch V <sub>OUT</sub> leakage	IUVLO OUT		-500	-	+500	nA	
Switch V <sub>IN</sub> leakage		V <sub>IN</sub> = 2.3 V	-	27	50	μΑ	
Overvoltage Protection	0010_11	- 111		I		<b> </b>	
OVP threshold	V <sub>OVP</sub>	$V_{IN}$ = 12 V, OVP rising, $T_A$ = 25 °C	1.14	1.2	1.26	V	
OVP hysteresis	OVPHST	$T_A = 25 \text{ °C}$	60	105	140	mV	
OVP leakage	I <sub>OVP</sub>	$V_{OVP} = 1.2$ V on the pin, $T_A = 25$ °C	-	40	100	nA	
IN pin internal fixed OVP	IN <sub>OVP</sub>	$T_{A} = 25 \text{ °C}$	23	24	25.6	V	
EN / UVLO		· A 0 0	20		2010	-	
EN on threshold	V <sub>UVPR</sub>	V <sub>EN</sub> rising	_	1.25	-	1	
EN off threshold	VUVPR	V <sub>EN</sub> falling	_	1.05	-	V	
EN / UVLO leakage	VUVPF	V <sub>EN</sub> Idamig V <sub>EN</sub> = 1.2 V	-0.25	-	+0.25	μA	
Overcurrent Protection		VEN - 1.2 V	0.20		10.20	μπ	
		Voltage that triggers the OCP					
Current limit voltage threshold	V <sub>OCP</sub>	shown on I <sub>LIM</sub> pin	-	0.6	-	VCu	
		$V_{IN}$ - $V_{OUT}$ = 1 V, $R_{SET}$ = 2.06 k $\Omega$	5.58	6	6.42		
Current limit accuracy	I <sub>OCP</sub>		3.22	3.5	3.78	А	
			1.32	1.5	1.68		
			0.43	0.5	0.58		
Current limit setting range		Minimum $R_{SET} = 2 \ k\Omega$	0.5	-	6		
Current limit hold-up time	t <sub>ILIM</sub>	Current limiting timeout, if no OTP	3	6	9	ms	
Power Switch							
ON resistance	R <sub>DS(ON)</sub>	$V_{IN}$ = 5 V to 22 V, $I_{OUT}$ = 1 A, $T_J$ = 25 °C	-	33	41	mΩ	
	US(ON)	$V_{IN} = 5 V \text{ to } 22 V, I_{OUT} = 1 A, T_J = 85 ^{\circ}\text{C}$		-	48	11152	
PGD, Power Good						-	
PGD pull-down resistance	R <sub>PG</sub>	$V_{IN} = 5 V$ , output pin = 0.1 V	-	5.2	10	Ω	
PGD oll leakage	I <sub>PG</sub>	Biased with 5 V <sub>DC</sub>	-	0.01	1	μA	
Switching Characteristics							
EN / UVLO						-	
Switch turn-on delay time	T <sub>ON_DLY</sub>	From EN / UVLO voltage, V <sub>UVPR</sub> to V <sub>OUT</sub> reaches 10 % V <sub>IN</sub> , R <sub>L</sub> = 10 $\Omega$ , C <sub>L</sub> = 10 $\mu$ F, C <sub>SS</sub> open	-	220	-	μs	
Shutdown delay	T <sub>OFF_DLY</sub>	$ \begin{array}{l} \mbox{From EN / UVLO low to } V_{OUT} = 0.9 \mbox{ x } V_{IN}, \\ R_L = 10 \ \Omega, \ C_L = 10 \ \mu F, \ C_{SS} \ open \end{array} $	-	10	-		
OVP Timing							
OVP off time	t <sub>OVP</sub>	$ \begin{array}{l} R_{L} = 100 \; \Omega, \; C_{L} = 0 \; \mu F, \; OVP \; steps \; from \; 1 \; V \; to \\ 1.4 \; V; \; measured \; from \; OVP \; pin \; voltage \\ crossing \; 1.2 \; V \; threshold \; to \; V_{OUT} = 0.9 \; x \; V_{IN} \end{array} $	-	0.3	1		
Internal OVP off time	t <sub>OVP_INT</sub>	$ \begin{array}{l} R_{L} = 100 \; \Omega, \; C_{L} = 0 \; \mu F, \; V_{IN} \; \text{steps from 22 V to} \\ 26 \; V; \; \text{measured from } V_{IN} \; \text{pin voltage crossing} \\ 24 \; V \; \text{threshold to } V_{OUT} = 0.9 \; x \; V_{IN} \end{array} $	-	1.5	-	μs	
Flag reporting delay		PGD pull up to 5 V through a 100 kΩ; delay time from OVP pin voltage step to PGD is below 0.5 V	-	-	2		
Overcurrent protection							
Moderate overcurrent protection	t <sub>OCP</sub>	Load current is 120 % of current limit threshold	-	1.1	-	μs	

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ELECTRICAL SPECIFICATIONS							
		TEST CONDITIONS UNLESS SPECIFIED	LIMITS				
PARAMETER	SYMBOL	$V_{IN}$ = 12 V, T <sub>J</sub> = -40 °C to +125 °C, $V_{EN(H)}$ = 2.4 V, C <sub>OUT</sub> = 0.1 µF, R <sub>LIM</sub> = 4.1 kΩ	MIN.	TYP.	MAX.	UNIT	
Soft Start Control							
Output rise up time	+		-	560	-	μs	
Output lise up time	t <sub>R</sub>		-	4.7	-	ms	
SS charge current			-	5	-	μA	
Auto Retry							
Auto retry cycle	RTY <sub>cnt</sub>	Delay time of restart after all faults are removed; this is defined as the number of cycles of soft start time set by C <sub>SS</sub>	-	32	-		
Thermal Shutdown							
Thermal shutdown		Temperature increases	-	165	-	°C	
Thermal shutdown hysteresis			-	45	-	°C	

### PACKAGE OUTLINE

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DFN10, pin 1 dot marking is on top of the device

Fig. 2 - Pin Out Drawing (top view)

PIN DESCRI	PTION	
PIN #	NAME	FUNCTION
1, 2	V <sub>IN</sub>	Power switch input pins; two pins are fused inside the package
3	SS	A capacitor from this pin to GND sets output voltage slew rate
4	EN / UVLO	Active high switch control input; $V_{THL} < 0.3 V$ , $V_{THH} > 1.4 V$
5	I <sub>LIM</sub> / I <sub>MON</sub>	A resistor from this pin to GND sets the overload and short-circuit current limit; the pin can be used for current reporting, referring to the voltage developed over the current limit setting resistor
6	GND	Ground
7	OVP	Input for setting the programmable overvoltage protection threshold. An overvoltage event turns-off the internal FET and asserts FLT to indicate the overvoltage fault
8	PGD	Open drain output, when $V_{OUT}$ is $\geq$ 95 % $V_{IN},$ and none of the following faults are triggered: OT, OC, OV
9, 10	V <sub>OUT</sub>	Power switch output pins; two pins are fused inside the package
Exposed pad	GND	The package's central exposed pad must be connected to the ground plane; optimal PCB thermal design will enhance device performance

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#### FUNCTIONAL BLOCK DIAGRAM AND TRUTH TABLE

TRUTH TABLE	
EN	SWITCH
1	ON
0	OFF



Fig. 3 - Device Block Diagram



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Fig. 5 - Quiescent Current vs. Temperature



Fig. 6 - Shutdown Current vs. Input





Fig. 9 - Shutdown Current vs. Temperature

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Fig. 10 - Switch Off Current vs. Temperature



Fig. 11 - On Resistance vs. Temperature



Fig. 12 - Soft Start Current vs. Input Voltage VIN



Fig. 13 - Threshold Voltage vs. Input Voltage VIN



Fig. 14 - Soft Start Current vs. Temperature



Fig. 15 - EN Current vs. EN Voltage

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Fig. 16 - Enable Resistance vs. Temperature



Fig. 17 - Rise Time vs. Temperature



Fig. 18 - Turn On Delay Time vs. Temperature



Fig. 19 - Turn Off Delay Time vs. Temperature



Fig. 20 - OVP Voltage vs. Temperature

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1 ms/div





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10 ms/div



V<sub>IN</sub> (5 V/div)

PGD (5 V/div)

I<sub>OUT</sub> (2 A/div)

EN (5 V/div)

SS (2 V/div)

I<sub>OUT</sub> (2 A/div)

V<sub>OUT</sub> (5 V/div)



Fig. 26 - Turn On by EN Into Resistive Load

 $V_{IN}$  = 12 V,  $R_L$  = 6  $\Omega$ ,  $C_{SS}$  = 133 nF,  $R_{LIM}$  = 1.74 k $\Omega$ 



V<sub>OUT</sub> (5 V/div)



Fig. 21 - Turn On by EN

 $V_{IN} = 12 V, R_L = 6 \Omega, C_L = 220 \mu F, C_{SS} = 22 nF, R_{LIM} = 1.74 k\Omega$ 



**TYPICAL CHARACTERISTICS** 

EN (5 V/div) PGD (5 V/div) I<sub>OUT</sub> (2 A/div)

V<sub>OUT</sub> (5 V/div)

SIP32434

10 ms/div ase -20.0 ms Trigger C 10.0 msidiv Normal 1.

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Fig. 28 - Turn On Into Output Short V<sub>IN</sub> = 12 V, C<sub>SS</sub> = 133 nF, I<sub>LIM</sub> = 1.74 k $\Omega$ 

EN (5 V/div)						
FLG (5 V/div)						
sS (5 V/div)	MW	WWW	WWW	www.	NM MM	MMMMM
	1				1	
I <sub>OUT</sub> (2 A/div)						
· · · · · · · · · · · · · · · · · · ·						- 200 ms/div -





Fig. 30 - Turn On by EN Into OCP Load V<sub>IN</sub> = 12 V, R<sub>L</sub> = 2  $\Omega$ , C<sub>L</sub> = 220 µF, C<sub>SS</sub> = 133 nF, R<sub>LIM</sub> = 1.74 k $\Omega$ 



Fig. 31 - Output Short With a 2  $\Omega$  Load V<sub>IN</sub> = 12 V, R<sub>L</sub> = 2  $\Omega$ , C<sub>SS</sub> = 133 nF, R<sub>LIM</sub> = 1.74 k $\Omega$ 



Fig. 32 - Over Current Protection Increase Load Current Slowly  $V_{IN}$  = 12 V, C<sub>L</sub> = 220 µF, C<sub>SS</sub> = 133 nF, R<sub>LIM</sub> = 1.74 k $\Omega$ 

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Fig. 33 - Over Voltage Protection  $R_L$  = 12  $\Omega$ ,  $C_L$  = 100  $\mu$ F,  $C_{SS}$  = 27 nF,  $R_{LIM}$  = 1.74 k $\Omega$ , OVP Set to 15.6 V



#### **OVERVIEW**

The SIP32434A and SIP32434B are eFuses with comprehensive integrated control features that simplify the design and increase the reliability of the circuitry connected to the switch.

The 32 m $\Omega$  switches are designed to operate in the 2.8 V to 23 V range. An internally generated gate drive voltage ensures good R<sub>ON</sub> linearity over the input voltage operating range.

The devices start their operation by checking the  $V_{IN}$ ,  $V_{OUT}$ , OVP, and EN / UVLO pins. When the voltages are in the ranges without exceeding under- or over-voltage protection thresholds, the PGD open drain switch is off. A high level on the EN / UVLO pin enables the internal MOSFET to start conducting and allows current to flow from IN to OUT. When EN / UVLO is held low, the internal MOSFET is turned off.

After a successful turn-on sequence, the device now actively monitors its load current, input voltage, and protects the load from harmful over-current, and over-voltage conditions. A built-in thermal sense circuit will detect junction over temperature and shut down the switch for safety.

#### SWITCH ON / OFF, AND UNDER-VOLTAGE LOCK OFF PROTECTION - UVLO

EN / UVLO pin controls the on / off of the power switch. When EN / UVLO is at a logic high the switch is on. When EN / UVLO is at a logic low, the switch is off.

The SIP32434A and SIP32434B implement under-voltage protection on the EN / UVLO to turn off the output. It is a user-defined under-voltage protection setting to flexibly select the proper minimum applied voltage for the downstream load or the device's proper operation.

The diagram shows how a resistor divider from supply to GND can be used to set the UVLO set point for a given voltage supply level.



The resistors must be sized large enough to minimize the constant leakage from supply to ground through the resistor divider network. At the same time, keep the current through the resistor network sufficiently larger than the leakage current on the EN / UVLO pin to minimize the error in the resistor divider ratio.

$$\mathsf{R}_{\mathsf{EN1}} = \frac{\mathsf{R}_{\mathsf{EN2}}(\mathsf{V}_{\mathsf{IN}} - \mathsf{V}_{\mathsf{UVPR}})}{\mathsf{V}_{\mathsf{UVPR}}}$$

Where V<sub>UVPR</sub> is 1.25 V.





UVLO turn off delay (T<sub>OFF DLY</sub>) is typically 550 µs and turn on delay T<sub>ON DLY</sub> is typically 500 µs.



Fig. 35 - Switching Times

#### **OVER-VOLTAGE PROTECTION (OVP)**

The SIP32434A and SIP32434B implement overvoltage protection (OVP) on both the VIN and OVP pins to protect the output load in the event of an input over-voltage. When the input exceeds the over-voltage protection thresholds V<sub>OVP(R)</sub> or the IN<sub>OVP</sub>, which is typically 24 V, the device turns off the output within toVP, while the PGD asserts in the meantime. As long as an over-voltage condition is present on the input, the device stays disabled and the output will be turned off. Over-voltage is a non-latchable fault. Once the input voltage returns to the normal operating range, the device attempts to start up normally.



V<sub>IN(OVP)</sub> - 1.2 V R<sub>OVP1</sub> R<sub>OVP2</sub> 1.2 V

OVP voltage divider resistors total resistance should not be over 2.5 M $\Omega$ .



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#### **INRUSH CURRENT, AND OVER-CURRENT PROTECTION**

The SIP32434A and SIP32434B incorporate two protections against over-current:

- Adjustable slew rate (SR) for inrush current control
- Adjustable over-current protection / active current limit to protect against overload conditions

The over-current protection (OCP) is active also during soft start. The over-current protection circuit controls the switch impedance to limit the current to the level programmed by the R<sub>SET</sub> resistor.

If the over-current condition persists for more than 6 ms (typ.), the switch shuts off and alert the drain FLG is asserted, pulling the pin to GND.

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#### **SLEW RATE CONTROL**

An inrush current happens when the switch turns on into a large output capacitance. If the inrush current is not controlled, it can damage the input connectors and / or cause the system power supply to droop, leading to unexpected restarts elsewhere in the system.

The SIP32434A and SIP32434B provide integrated output slew rate control to manage the inrush current during start-up. This is achieved by forcing the V<sub>OUT</sub> to follow the voltage on a soft start capacitor. A constant current source of 5 µA charges the  $C_{SS}$ , generating a linear ramp up voltage on  $C_{SS}$ .

The inrush current is proportional to the load capacitance and rising slew rate. The following equation can be used to calculate the slew rate required to limit the inrush current (I<sub>INRUSH</sub>) for a given load capacitance (C<sub>OUT</sub>):

> SR (V/ms) =  $\frac{I_{INRUSH} (mA)}{C_{OUT} (\mu F)}$  $T_{SS} = \frac{V_{IN}}{SR} = V_{IN} \times \frac{C_{OUT} (\mu F)}{I_{INRUSH} (mA)}$

An external capacitor can be connected to the soft start (SS) pin to control the rising slew rate and lower the inrush current during turn-on. The output voltage follows the required C<sub>SS</sub> capacitance to produce a given slew rate, which can be calculated using the following formula:

$$C_{SS} = \frac{(I_{SS} \times 9)}{SR}$$

The fastest output slew rate is achieved by leaving the soft start pin open.

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PGD is pulled through a resistor to an external voltage source

Fig. 38

#### **CURRENT LIMIT SETTING**

The SIP32434A and SIP32434B actively monitor the current flow through the switch and provide a quick response to over-current conditions by actively regulating the current to a set limit. The current limit is set by connecting a resistor between the  $I_{LIM}$  pin and GND.  $R_{SET}$  can be calculated by the following formula for a desired current limit:

 $SR (V/ms) = \frac{I_{INRUSH} (mA)}{C_{OUT} (\mu F)}$  $R_{SET} = \frac{0.6 V}{I_{LIM}} \times 20 600$ 

When the load current exceeds the threshold ( $I_{LIM}$ ), the parts respond within 1 µs (typ.) to turn off the switch and then regulate the switch gate voltage to limit the output current to the set  $I_{LIM}$  level. During this brief period before the over-current protection circuit is engaged, the parts will see a surge current, especially under a severe output short condition. The magnitude of the surge current developed during the period when the over-current protection is not engaged is determined by impedance in the loop from the input current source to ground and the response time. This impedance is the sum total of the current source impedance, the path resistance and inductance, and the load impedance.

If the over-current condition persists for more than 6 ms / typ., the switch shuts off. When  $V_{OUT}$  falls below 95 % of  $V_{IN}$ , the PGD is pulled low. The device will exit current limiting when the load current falls below  $I_{LIM}$  before the end of the current limit period. The control circuit will increase the gate drive in the same manner as the soft start when the switch exits from the current limit mode.

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The current limit mode could result in excessive power on the switch, which increases the  $T_J$  quickly. The SIP32434A and SIP32434B have OTP, providing an enhanced level of production.

Once the device is off due to OCP or OTP faults, the SIP32434A stays in the latch-off state and the SIP32434B auto-retries after 32 times of the programmed soft start time. They can be reset by toggling  $V_{IN}$  or EN / UVLO.



PGD is pulled through a resistor to an external voltage source

Fig. 39 - Over-Current Protection



PGD is pulled through a resistor to an external voltage source

Fig. 40 - Turn On Into Over-Current Load



#### **OTP, OVER-TEMPERATURE PROTECTION**

Over-temperature protection turns off the power switch when the die temperature reaches the OTP threshold of 165 °C. The hysteresis is 45 °C. When the die temperature drops below 120 °C, it is allowed to turn on again.

#### PGD, POWER GOOD REPORTING

PGD is an open drain output. A pull-up resistor must be connected pulling to 3 V or 5 V. It is asserted low when  $V_{OUT}$  is below 95 % of  $V_{IN}$ , or an over-current, over-voltage, or over-temperature fault condition occurs.

#### INPUT CAPACITOR

While bypass capacitors at the input pins are not required, a 2.2  $\mu$ F or larger capacitors for C<sub>IN</sub> is recommended in almost all applications. The bypass capacitors should be placed as physically close to the device's input pins and ground to be effective to minimize transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries. For hot-plug applications, where input path inductance is negligible, this input capacitor can be minimized or eliminated.

#### **OUTPUT CAPACITOR**

The SIP32434A and SIP32434B do not require an output capacitor for proper operation. A proper value C<sub>OUT</sub> is recommended to accommodate load transient per circuit design requirements. There are no ESR or capacitor type requirements. Protection

#### LAYOUT GUIDELINES

The SIP32434A and SIP32434B are protection switches designed to maintain a constant output load current upon over-current fault. Optimized layout with efficient heat sinking is critical. It is recommended to put as much copper as possible to the devices' central exposed pad which is connected to ground. Connect all ground planes with all possible thermal VIAs.

The circuit setting components should be laid close to their connection pins. The components include current limit setting resistor, soft start setting capacitor, and resistors connected to EN / UVLO and OVP pins.

Protection devices such as input TVS or output Schottky diodes must be located close the pins to be protected and routed with short traces to reduce inductance.

Below is a layout example.



Fig. 41



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# SIP32434

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PRODUCT SUMMARY		
Part number	SIP32434A	SIP32434B
Description	6 A, 33 mΩ, 2.8 V to 23 V, programmable OVP and current limit, latch-off on fault	6 A, 33 mΩ, 2.8 V to 23 V, programmable OVP and current limit, auto retry on fault
Configuration	Single	Single
Slew rate time (µs)	Adjustable	Adjustable
On delay time (µs)	190	190
Input voltage min. (V)	2.8	2.8
Input voltage max. (V)	28	28
On-resistance at input voltage min. (m $\Omega$ )	33	33
On-resistance at input voltage max. (m $\Omega$ )	33	33
Quiescent current at input voltage min. (µA)	180	180
Quiescent current at input voltage max. (µA)	250	250
Output discharge (yes / no)	N	N
Reverse blocking (yes / no)	N	N
Continuous current (A)	6	6
Package type	DFN33-10L	DFN33-10L
Package size (W, L, H) (mm)	3.0 x 3.0 x 0.9	3.0 x 3.0 x 0.9
Status code	Active	Active
Product type	Slew rate, current limit	Slew rate, current limit
Applications	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable

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#### DFN-10 LEAD (3 X 3)







		MILLIMETERS			INCHES			
	Dim	Min	Nom	Max	Min	Nom	Max	
and inches.	Α	0.80	0.90	1.00	0.031	0.035	0.039	
	A1	0.00	0.02	0.05	0.000	0.001	0.002	
	A3	0.20 BSC			0.008 BSC			
terminal and is measured terminal tip.	b	0.18	0.23	0.30	0.007	0.009	0.012	
d heat sink slug as well as the	D	3.00 BSC			0.118 BSC			
	D2	2.20	2.38	2.48	0.087	0.094	0.098	
r a mold or marked feature, it ndicated.	E	3.00 BSC			0.118 BSC			
luicaleu.	E2	1.49	1.64	1.74	0.059	0.065	0.069	
	е	0.50 BSC			0.020 BSC			
	L	0.30	0.40	0.50	0.012	0.016	0.020	
	*Use millimeters as the primary measurement.							
	ECN: S-42 DWG: 594		4, 29-Nov-04					

#### NOTES:

- 1. All dimensions are in millimeters and inches.
- 2. N is the total number of terminals.



<u>/5</u>

Dimension b applies to metallized terminal and is between 0.15 and 0.30 mm from terminal tip.

Coplanarity applies to the exposed heat sink slug as well as the terminal.

The pin #1 identifier may be either a mold or marked feature, it must be located within the zone iindicated.





# Recommended Minimum PAD for DFN10 3 mm x 3 mm



Note: Dimension are in millimeters

ECN: S22-0379-Rev. A, 02-May-2022 DWG: 3008

**Recommended Land Pattern vs. Case Outline** 





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